Broadband Amplified Spontaneous Emission and Random Lasing from Wurtzite CdSe/CdS “Giant-Shell” Nanocrystals

Francesco Di Stasio,†,‡ Anatolii Polovitsyn,†,‡ Ilaria Angeloni,†,§ Iwan Moreels, † and Roman Krahne*†

†Nanochemistry Department, Istituto Italiano di Tecnologia, Via Morego 30, Genoa 16163, Italy
‡Dipartimento di Fisica and 4Dipartimento di Chimica e Chimica Industriale, Università degli Studi di Genova, Via Dodecaneso 33, Genoa 16146, Italy

Supporting Information

ABSTRACT: Colloidal nanocrystals (NCs) are attractive materials for light-emitting applications thanks to their flexible synthesis, size-dependent properties, and bright emission. Yet, colloidal NCs still present a narrow gain band (full-width half-maximum around 10 nm), which limits their application to single-color lasers. Widening of the gain band by specifically engineered NCs can further improve the prospect of this class of materials toward the fabrication of solution-processed white-emitting or color-tunable lasers. Here, we report broadband amplified spontaneous emission (ASE) from wurtzite CdSe/CdS “giant-shell” nanocrystals (g-NCs) with an unprecedented large core up to 7.5 nm in diameter that were synthesized through a continuous injection route. The combination of large core and shell enables ASE from different CdSe optical transitions as well as from the CdS. Importantly, thin films of g-NCs with a large CdSe core (7.5 and 5.1 nm in diameter) show ASE at different colors with a similar threshold, indicating that light emission amplification can be achieved from different optical transitions simultaneously. Tuning of the core diameter allows obtaining ASE in a wide spectral range, and blending of g-NCs with different core sizes gives rise to a continuous amplified spontaneous emission band from green to red (510 to 650 nm). Drop-cast films of CdSe/CdS g-NCs demonstrate simultaneous dual-color random lasing under nanosecond-pulsed excitation.

KEYWORDS: giant-shell nanocrystals, CdSe/CdS, broadband, amplified spontaneous emission, random lasing

Development of novel semiconductor gain materials for lasers has seen a conspicuous increase in research effort in recent years. A variety of semiconductors able to sustain optical gain in the visible range are available, with colloidal nanocrystals (NCs) and 2D materials being among the most actively investigated. Currently, within the family of solution-processed materials, colloidal CdSe/CdS and perovskite NCs demonstrate the lowest stimulated emission threshold in the visible spectrum. Colloidal semiconductor NCs based on CdSe/CdS core–shell structures have been extensively studied as gain material since the demonstration of stimulated emission, while the development of inorganic and hybrid perovskite NCs for lasing applications has just started. Amplified spontaneous emission (ASE) and stimulated emission thresholds as low as a few μJ/cm² have been reported for CdSe/CdS core–shell NCs due to optimized synthesis and the reduction of Auger recombination by interfacial engineering and shape control. Typically, colloidal NCs present a relatively narrow optical gain band positioned at the band-edge photoluminescence (PL) peak (full-width half-maximum, fwhm, around 10 nm). Broadening of the optical gain band can pave the way to solution-processed wavelength-tunable lasers or white-emitting lasers, which will remove the necessity of using NCs of different composition or sizes or blends of different semiconducting conjugated polymers for such applications. Specific architectures such as CdSe/CdS core–shell dot-in-rods (DiRs) and giant-shell NCs (g-NCs) can show ASE from the CdSe and the CdS components depending on the core/shell volume ratio and the overall size of the shell, thus enabling optical gain in the green and red part of the visible spectrum. Importantly, g-NCs present a further advantage over DiRs, since they demonstrate gain from two different CdSe core transitions in addition to the shell, as reported by F. Garcia-Santamaria et al. This phenomenon has been observed for g-NCs with a relatively small (3 nm in diameter) zincblende CdSe core and a question arises if additional ASE peaks can be intentionally added by using larger cores exploiting higher energy levels or optical transitions. Furthermore, use of a large core will reduce the Auger rates, since the latter is proportional to 1/r³ (where r is the core radius).

For these reasons we have investigated a series of g-NCs with increasing core diameter. g-NCs obtained via a continuous injection route can be synthesized starting from wurtzite (WZ) CdSe cores, leading to a nearly defect-free epitaxial growth of a...
We expanded this synthetic approach to cores with a diameter up to 7.5 nm. Employing a large CdSe core enables further broadening of the ASE band; more specifically four distinct peaks can be observed. Varying the CdSe core diameter, while keeping an overall similar size among the different g-NCs samples allowed for fabrication of solid films consisting of a homogeneous blend leading to a continuous ASE band from 510 to 650 nm. Drop-cast g-NCs films show efficient random lasing from areas where cracks induce light scattering.\(^5,6\)

Importantly, the random lasing is observed at two different colors simultaneously and with similar intensity.

The g-NCs here investigated were synthesized using a continuous injection approach\(^26\) employing CdSe wurtzite cores previously prepared following the procedure in ref \(^17\). To obtain isotropic CdSe cores with a 7.5 nm diameter, the synthesis was slightly modified since the procedure of Carbone et al.\(^17\) yielded elongated CdSe cores when extending the reaction time.\(^29\) This anisotropic growth is likely caused by impurities in the trioctylphosphine oxide (TOPO) and octadecylphosphonic acid (ODPA) in the form of shorter phosphonic acids.\(^29,30\) Slightly reducing the concentration of ODPA, replacing it by an equivalent amount of tetradecylphosphonic acid (TDPA), on the other hand, allowed for the growth of isotropic CdSe cores with a diameter greater than 5.5 nm. In Figure SI1 we report the optical absorption spectra, photoluminescence spectra, transmission electron microscopy (TEM) images, and size distribution histograms of the five CdSe cores used in our study. Their diameter was determined via the optical absorption spectra, yielding 3.7, 4.1, 4.6, 5.1, and 7.5 nm.\(^31\) Good agreement is found with a size analysis via TEM (Figure SI1); for simplicity we will refer to the g-NCs cores previously prepared following the procedure in ref \(^17\) to obtain isotropic CdSe cores with a 7.5 nm diameter, the cores previously prepared following the procedure in ref \(^17\) for simplicity we will refer to the g-NCs cores previously prepared following the procedure in ref \(^17\) for simplicity we will refer to the g-NCs cores previously prepared following the procedure in ref \(^17\) for simplicity we will refer to the g-NCs cores previously prepared following the procedure in ref \(^17\) for simplicity we will refer to the g-NCs cores previously prepared following the procedure in ref \(^17\) for simplicity we will refer to the g-NCs (see Figure SI3 and Table SI1). The number of CdS monolayers (MLs) forming the shell ranges from 9 to 17 among the g-NCs. Figure 1 shows the PL and optical absorption spectra of the 3.7 and 7.5 nm g-NCs samples in dilute chloroform solutions (spectra from g-NCs with other core diameters are reported in Figure SI1 in the Supporting Information). Within the g-NC series we observe a PL red-shift of 23 nm when increasing the core size. All samples present a similar PL fwhm of 4 ± 3 nm and a similar absorption spectrum due to the “bulk-like” CdS shell. The CdSe core size has a significant impact on the PL quantum yield (QY) because a larger core diameter will enable a faster shell-to-core carrier relaxation rate due to a decreased shell/core volume ratio. This is confirmed by the range in PLQY from 25% to 53% that we measured, where we achieved the highest value for the largest core sample under shell excitation at 450 nm.\(^26\)

To assess the feasibility of our g-NCs as gain materials, we performed ASE measurements on drop-cast films on soda-lime glass slides.

Figure 2 shows the emission spectra recorded from a film of g-NCs with a 7.5 nm core diameter under femtosecond excitation at increasing pump fluence (the excitation beam was focused in a stripe for all these measurements). ASE from different excited states as well as from the CdS shell is observed. (b) Emission intensity vs excitation fluence curves for the different ASE peaks shown in panel (a).

![Figure 1](image1.png)

**Figure 1.** (a and b) TEM images of the two g-NCs samples: 3.7 and 7.5 nm core diameters. (c and d) Optical absorption (solid line) and PL spectra (dotted line) of CdSe/CdS g-NCs with 3.7 nm (c) and 7.5 nm (d) core diameters. A PL red-shift of 23 nm is observed when increasing the core size from 3.7 nm to 7.5 nm. Optical absorption, PL spectra, and TEM images for all other samples are shown in Figure S11. Optical absorption and PL spectra were collected from dilute g-NCs in chloroform.

![Figure 2](image2.png)

**Figure 2.** (a) Emission spectra under increasing femtosecond-pulsed excitation fluence with \(\lambda_{\text{exc}} = 405 \text{ nm} \) recorded from a drop-cast film of CdSe/CdS g-NCs with a 7.5 nm core diameter. The measurements were carried out using a cylindrical lens to focus the excitation beam into a stripe. ASE from different excited states as well as from the CdS shell is observed. (b) Emission intensity vs excitation fluence curves for the different ASE peaks shown in panel (a).
two ASE peaks could be due to sample polydispersity. The CdSe cores have a limited polydispersity of around 10%, but variations in the CdS shell thickness are clearly observed. Nevertheless, CdS shell thickness variations typically have only a limited impact on the spectral position of the PL (for a shell thickness $\geq 3$ nm), ruling out sample polydispersity as a possible explanation for the different emission peaks.\textsuperscript{32,33} Therefore, we attribute the ASE peaks to the band-edge emission at 648 nm and a higher energy optical transition of the g-NC sample. Furthermore, the band-edge ASE band is blue-shifted compared to the PL peak, likely due to a repulsive exciton–exciton interaction.\textsuperscript{5,27,34} Such a blue-shift of the band-edge ASE was observed for all core sizes (see Figures S2 and S3). With increasing pump fluence two additional ASE peaks appear at 566 and 538 nm, which can be assigned to a higher order CdSe core energy transition and the CdS shell (at 538 nm, as observed for CdSe/CdS DiRs with a large CdS rod length).\textsuperscript{21,35} The appearance of narrow emission peaks (fwhm values are reported in Table 2 of the Supporting Information) already indicates the presence of ASE. To confirm that the observed emission peaks originate from an ASE process, we performed time-resolved measurements (see Figure SI4). The time traces show a shortened temporal decay at high pump fluence for all peaks, which is a clear fingerprint of ASE.\textsuperscript{1,21}

We observe a similar behavior to the one reported in Figure 2 for all samples in our series, with ASE from different optical transitions (see Figures S12 and S13 in the Supporting Information). The minimum fluence to observe ASE varies from 45 to 105 $\mu$J/cm$^2$ throughout the sample series, and we find no clear correlation between core size and the onset of ASE, most likely due to the influence of the film morphology on the latter, as reported by C. Gollner et al.\textsuperscript{5}

The evolution of the ASE peaks and PL intensities versus excitation fluence for the largest core g-NCs is presented in Figure 2b, and it shows that the two ASE peaks observed at 648 and 612 nm occur at similar threshold and the latter presents an overall higher ASE intensity. The 5.1 nm core g-NCs sample (Figure SI3) also shows a similar ASE threshold for two different optical transitions. Decreasing the core size further results in ASE from an excited-state energy level that appears at higher threshold values compared to that of the band-edge transition. This can be explained by the increased exciton confinement for smaller CdSe cores, which leads to more efficient Auger recombination, thus hindering ASE from higher energy levels.\textsuperscript{36}

ASE from an additional (3rd) core transition is clearly observable for the largest core size g-NCs, while in the case of the 5.1 nm core diameter, this optical gain band is close to the CdS shell (at 546 and 536 nm, respectively). In samples with a smaller core size we observed only three ASE peaks: two from optical transitions of the CdSe core and a third one from the CdS shell.

The observed blue-shift of the ASE peak arising from the band-edge transition (throughout all our samples) suggests that optical gain is obtained through the formation of multie excitons, similar to what was previously observed for g-NCs.\textsuperscript{7} In order to achieve ASE from multie excitons, Auger recombination has to be strongly reduced, because Auger rates sharply increase with exciton density, efficiently preventing stimulated emission.\textsuperscript{5,37} We achieved this by the large core size and a large exciton volume in our g-NCs, where holes are strongly confined within the CdSe core and electrons are delocalized.\textsuperscript{7} Importantly, the two largest core samples show two ASE peaks at similar pump fluence, indicating that stimulated emission occurs simultaneously for two different optical transitions, and thus suggesting that the exciton cooling process from higher energy states is slowed down. Depopulation of high-energy states is typically very efficient and takes place within picoseconds.\textsuperscript{36} Considering that cooldown from high-energy levels (associated with the second and third ASE peaks) occurs through the emission of optical phonons of energy around 30 meV,\textsuperscript{38} possibly a “phonon bottleneck”\textsuperscript{34} prevents efficient energy dissipation, effectively decoupling the different states. This effect, combined with the suppression of Auger recombination for larger cores, can account for the similar threshold of the first and second ASE peaks (Figure 3b).

![Figure 3](image-url)

Figure 3. (a) Emission spectra at high excitation fluence for samples with different core size showing ASE from different transitions (dotted lines are guides for the eye). (b) Spectral position of the different ASE peaks vs core sizes (error bars represent the standard deviation).

As discussed above, all g-NC samples show ASE from different CdSe core emissive states and eventually from the CdS shell. By changing the core size, it is possible to tune the spectral position of the ASE arising from the different CdSe core transitions. In Figure 3a emission spectra at high pump fluence of the different g-NCs show a continuous transition toward longer wavelengths for all ASE peaks for increasing CdSe core diameter, as expected from the reduction in quantum confinement.\textsuperscript{36} Increasing the CdSe core diameter induces a red-shift of the band-edge ASE peak from 621 to 648 nm (see Figure 3b), while the subsequent gain band undergoes a stronger shift from 560 to 612 nm. ASE arising from a third CdSe optical transition can be clearly observed only for the largest core diameter samples, while for core diameters of 4.6 nm or smaller we expect this band to overlap the gain band.
observed from the CdS shell. The ASE peak observed from the CdS shell shows a red-shift with increasing core diameter as well, which could be caused by convolution of emission arising from core and shell states.\(^3\)

In the following we demonstrate that simple blending of g-NC solution with different core diameter, and consequently different positions of ASE peaks, can lead to the formation of a continuous optical gain band from red to green. We prepared films via drop-casting of a mixed solution of g-NCs in chloroform and show the emission spectra under femtosecond excitation with increasing pump fluence of a typical blend film (here core diameters were 7.5 and 4.1 nm) in Figure 4, where a continuous optical band from 510 to 650 nm is created.

In the blends, the threshold to obtain ASE is higher than for films from the two separated g-NCs components, which might be correlated to the density of g-NCs of one core size in the excitation spot. ASE is initially observed at 624 nm, which corresponds to the band-edge ASE for the 4.1 nm core sample (see Figure S13). On increasing the pump fluence, we observe the appearance of two other peaks, at 643 nm (band-edge ASE of the 7.5 nm core sample) and 572 nm (close to the second ASE peak observed for the 4.1 nm core sample). Finally, a continuous single band is obtained when the pump fluence is raised above 1.8 mJ/cm\(^2\). To assess the homogeneity of our blended film, we performed confocal imaging, recording the emission in narrow spectral bands centered at wavelengths that correspond to the two different PL peaks of the 4.1 and 7.5 nm g-NCs (657 and 662 nm, respectively). We did not observe significant differences in intensity in the spatial maps obtained in both spectral bands, which indicates good blending of the two phases. Likely, this was achieved due to the similar overall size of the two g-NC samples despite their different core diameters.

Figure 5a shows an optical microscope image of a film obtained by drop-casting of a solution of 7.5 nm g-NCs on glass, where a pattern of cracks that formed during solvent evaporation can clearly be observed. The cracks propagate for several micrometers in roughly orthogonal directions in certain areas of the film, forming large aggregates of g-NCs with areas up to 100 \(\mu\)m\(^2\). In contrast to typical random lasing structures \(^4\) that require an additional scattering medium, such a morphology can induce light scattering and optical feedback due to the relatively high refractive index of CdSe/CdS NCs (n \(\approx 2\))\(^1\) with respect to air. For example, coffee rings consisting of CdSe/CdS NCs can act as microresonators and show lasing.\(^1,2,35\)

Figure 5b shows efficient dual-color random lasing of a g-NC film from both the band-edge and a higher-energy core transition. Under femtosecond-pulsed excitation, two lasing peaks at 612 and 651 nm can be observed (fwhm 1.3 and 1.0 nm, respectively) that emerge at a pump fluence of 22 \(\mu\)J/cm\(^2\). At high pump fluence (31 \(\mu\)J/cm\(^2\) and above) the spectra show sets of narrow peaks with an envelope that resembles the shape of the ASE bands. We can evaluate the average mode spacing (\(\Delta\lambda\)) in each band and obtain 2.3 nm at the band edge and 3.5 nm for the higher energy band. From this mode spacing we can estimate the respective cavity round-trip length (\(s = \lambda^2/(n\Delta\lambda)\)) as 92 and 53 \(\mu\)m.\(^6\) This indicates that the laser modes for the two different transitions originate from different random cavity paths within the film. Importantly, under femtosecond-pulsed excitation we observe lasing at two colors with the same, low pump threshold (22 \(\mu\)J/cm\(^2\)) similar to the ASE behavior (see Figure 2). Measurements performed with nanosecond-pulsed excitation show a lasing threshold around 490 \(\mu\)J/cm\(^2\) at the band edge (651 nm), and a set of peaks can be clearly resolved at higher pump fluence. Above 1420 \(\mu\)J/cm\(^2\) we observe three
distinct peaks with an average fwhm of 0.6 nm (close to the resolution limit of our spectrometer) and mode spacing Δλ around 2.3 nm. On increasing the excitation to 2790 μJ/cm², lasing corresponding to the second ASE band is observed in the form of an additional peak at 613 nm with a fwhm of 1.0 nm (see Figure 5c). We note that absolute values for lasing threshold between femtosecond and nanosecond excitation are difficult to compare because the threshold depends on local film morphology, and the spectra were not recorded from exactly the same area. Under nanosecond excitation lasing from the higher energy band emerges only at high pump fluence, indicating that on this time scale Auger recombination and electron cooling are more dominant than under femtosecond excitation.

In conclusion, we have developed a modified continuous injection route26 that allowed us to synthesize WZ/WZ g-NCs with a core diameter up to 7.5 nm. Such large-core g-NCs are able to sustain ASE from four different optical transitions. Therefore, g-NCs with large CdSe cores have a clear advantage compared to other core-shell architectures, since they demonstrate simultaneous ASE at different colors (i.e., with similar threshold and intensity). Blending of two g-NC samples leads to the formation of a homogeneous solid-state film due to the similar overall sizes of the NCs despite the different core diameters. Such films show a continuous ASE band from 510 to 650 nm, thus paving the way to solution-processed gain materials that can be used for the fabrication of white or wavelength-tunable lasers. Another demonstration of the potential of large core g-NCs for laser applications is the presence of simultaneous dual-color lasing of similar intensity obtained from drop-casted films presenting cracks and inhomogeneity. Such systems present dual-color random lasing even under nanosecond-pulsed excitation.

## EXPERIMENTAL SECTION

### Chemicals.
Triocleyolphosphine oxide (99%), triocleyolphosphine (97%), sulfur (99%), and selenium (99.99%) were purchased from Stem Chemicals. Octadecylphosphonic acid (99%) and tetraocleyolphosphoric acid (99%) were purchased from Polycarbon Industries. Cadmium oxide (99.5%), 1-octadecene (90%), and oleic acid (90%) were purchased from Sigma-Aldrich.

### Sample Preparation.
The CdSe cores of different diameters were synthesized at 380 °C following the procedure reported in ref 17. To obtain CdSe cores with a 7.5 nm diameter, we used a mixture of TDDPA and ODPA in a 15:85 mass ratio instead of pure ODPA. Then a CdSe shell was grown as in ref 26, and the obtained CdSe/Cds g-NCs were dispersed in chloroform. Films used for the ASE and lasing measurements were prepared via drop-casting of the chloroform g-NC solution onto previously cleaned soda-lime glass slides under air. The same film preparation was used for the blended film where a solution of mixed 4.1 and 7.5 nm core diameter g-NCs was employed.

### Sample Characterization.
Optical absorption spectra were collected from dilute chloroform solutions with a Cary 5000 UV−vis−NIR spectrophotometer from Agilent Technologies, while the fluorescence spectra below 1000 nm were measured with an Edinburgh Instruments fluorescence spectrometer (FLS920) equipped with a calibrated integrating sphere. g-NC solutions for PL and PLQY measurements were prepared in quartz cuvettes and carefully diluted to 0.1 optical density at the excitation wavelength (λ = 450 nm). TEM images were acquired using a JEOL-1100 TEM operating at an acceleration voltage of 100 kV.

### ASE and Laser Emission Measurements.
Films of CdSe/Cds g-NCs were excited with λ = 405 nm using an amplified Ti:sapphire laser (Coherent Legend Elite seeded by a Ti:sapphire fs laser) with a 70 fs pulse (fwhm) and a repetition rate of 1 kHz. The ASE measurements were performed by focusing the excitation beam with a cylindrical lens onto the sample, thus obtaining a stripe-shaped beam profile. All ASE spectra were collected at ~90° with respect to the excitation beam. Laser emission measurements on the drop-casted films were carried out using a spherical lens. For nanosecond-pulsed excitation a Spectra-Physics Explorer laser diode (λlaser = 349 nm, 3 ns pulse fwhm, repetition rate 1 kHz) was used. All steady-state emission spectra from films were collected with an Ocean Optics HR4000 spectrometer coupled to an optical fiber. For time-resolved emission spectra below and above threshold a Hamamatsu Photonics streak camera was employed. Emission intensities used in the intensity versus excitation fluence curves (Figure 2b, Figures S12 and S13) were obtained via a multipeak fit with two Gaussians to fit the ASE and PL peaks.

### Optical Microscope Image.
The optical microscope image reported in Figure 5a was acquired in reflection mode using a Nikon microscope with a 60x objective.

## ASSOCIATED CONTENT

### Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acsphotonics.6b00452.

TEM images and light emission data from all samples of the series (PDF)

## AUTHOR INFORMATION

### Corresponding Author

*E-mail: roman.krahne@iit.it.

### Author Contributions

“F. Di Stasio and A. Polovitsyn contributed equally.

### Notes

The authors declare no competing financial interest.

### ACKNOWLEDGMENTS

The research leading to these results has received funding from the CARIPLO Foundation through the project “NANO-CRYSLAS” and from the Ministero degli Affari Esteri e della Cooperazione Internazionale (IONX-NC4SOL). We thank Marco Scotto for valuable technical assistance.

## REFERENCES